NSN 5961-01-326-0617

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View Online at https://aerobasegroup.com/nsn/5961-01-326-0617 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case and burn in **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 800.0 collector to emitter voltage/static/base open and 1000.0 collector to base voltage/static/emitter open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 7.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 50.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:**

Fiig: A110a0

No

Demilitarization: